

1. Record Nr.	UNINA9910787223303321
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Titolo	Linearization and efficiency enhancement techniques for silicon power amplifiers : from RF to mmW // Eric Kerherve, Didier Belot
Pubbl/distr/stampa	Oxford, England : , : Academic Press, , 2015 ©2015
ISBN	0-12-418681-5
Descrizione fisica	1 online resource (163 p.)
Disciplina	621.381325
Soggetti	Power amplifiers Amplifiers, Radio frequency
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Description based upon print version of record.
Nota di bibliografia	Includes bibliographical references.
Nota di contenuto	Front Cover; Linearization and Efficiency Enhancement Techniques for Silicon Power Amplifiers; Copyright Page; Contents; List of Contributors; 1 Holistic Approaches for Power Generation, Linearization, and Radiation in CMOS; 1.1 Self-Healing Integrated Circuits; 1.1.1 Self-Healing mm-Wave Power Amplifier; 1.1.2 Sensing RF Power; 1.1.3 Sensing DC Current; 1.1.4 Actuating Quiescent Operating Point; 1.1.5 Data Conversion and Healing Algorithm; 1.1.6 Measurement Results; 1.2 Segmented Power Mixer for mm-Wave Transmitters; 1.2.1 Key Building Blocks; 1.2.2 Measurement Results 1.3 Distributed Active Radiation1.3.1 DAR Design Approach; 1.3.2 Architecture; 1.3.3 Measurement Results; References; 2 Cartesian Feedback with Digital Enhancement for CMOS RF Transmitter; 2.1 Introduction; 2.2 CFB Loop; 2.3 CFB Digital Part Implementation; 2.3.1 Phase Estimation; 2.3.1.1 "atan"-Based Architecture; 2.3.1.1.1 LUT-Based Architecture; 2.3.1.1.2 CORDIC-Based Architecture; 2.3.1.2 "Modulo" Function Implementation; 2.3.2 Vector Rotation; 2.3.2.1 LUT and Multipliers Solution; 2.3.2.2 CORDIC-Based Solution; 2.3.3 Subtraction; 2.3.4 Improvement of CFB CORDIC-Based Architecture 2.3.4.1 Modification of the CFB Algorithm2.3.4.2 New Architecture; 2.4 Analog Part Implementation; 2.5 Linearized Transmitter Results; 2.6 Power Consumption and Size Considerations; 2.7 Conclusion; References; 3 Transmitter Linearity and Energy Efficiency; 3.1

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Sommario/riassunto

Learn how to design and linearize high performance silicon power amplifiers, improving efficiency and solving problems and trade-offs of power amplifier design

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